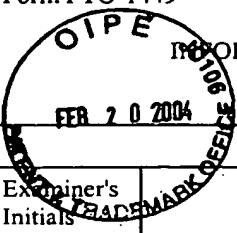


Form PTO-1449					Docket No. P02,0480		Serial No. 10/706,067	
 <b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b> (use several sheets if necessary)					Romney R. Katti et al.		Group Art Unit	
					Filing Date November 12, 2003			
<b>U.S. PATENT DOCUMENTS</b>								
Examiner's Initials		Document Number	Date	Name	Class	Subclass	Filing Date If appropriate	
JM	AA	5,695,864	12/09/97	Slonczewski				
JM	AB	5,966,322	10/12/99	Pohm et al.				
JM	AC	5,949,707	09/07/99	Pohm et al.				
JM	AD	6,317,359 B1	11/13/01	Black et al.				
JM	AE	6,392,924 B1	05/21/02	Liu et al.				
	AF							
	AG							
	AH							
	AI							
<b>FOREIGN PATENT DOCUMENTS</b>								
		Document Number	Date	Country	Class	Subclass	Translation Yes No	
	AJ							
	AK							
	AL							
	AM							
	AN							
	AO							
	AP							
	AQ							
<b>OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)</b>								
JM	AR	James Daughton, "Magnetoresistive Random Access Memory (MRAM), 2/4/00, pgs. 1-13.						
	AS							
	AT							
	AU							
	AV							
	AW							
Examiner		/John McPherson/		Date Considered 05/10/2006				
<b>*EXAMINER:</b> Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.								